

ECN HISTORY LIST					
REV	DATE	DESCRIPTION	APPROVED	CHECKED	DRAWN
1.0	17/05/27	新發行	羅宜春	梁周虎	張光
備 注					

1. Features

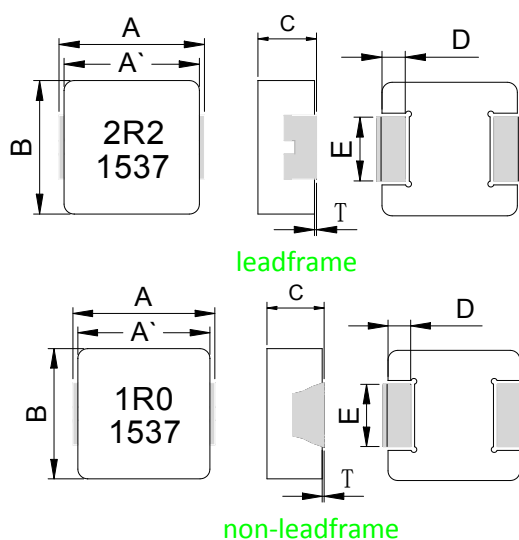
1. Shielded construction.
2. Capable of corresponding high frequency (5MHz).
3. Low loss realized with low DCR.
4. High performance (Isat) realized by metal dust core.
5. Ultra low buzz noise, due to composite construction.
6. 100% Lead(Pb)-Free and RoHS compliant.



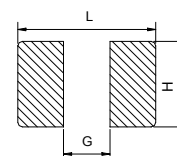
2. Applications

1. DC/DC converters in distributed power systems.
2. DC/DC converter for Field Programmable Gate Array(FPGA).
3. Battery powered devices.
4. Thin type on-board power supply module for exchanger.
5. VRM for server.
6. High current, low profile POL converters.
7. PDA/notebook/desktop/server and battery powered devices.

3. Dimensions



Recommend PC Board Pattern



Series	A	A'	B	C	D	T	E	Inductance
TMPA1004	11.0±0.3	10.0±0.3	10.0±0.3	3.8±0.2	2.0±0.3	0~0.2	2.5±0.3	0.56~1.50uH among
							3.0±0.3	0.47uH and below 2.00uH and above

Unit:mm

4. Part Numbering

TMPA	1004	S	-	1R0	MN	-	D
A	B	C		D	E		F

A: Series

B: Dimension

C: Type

D: Inductance

E: Inductance Tolerance

F: Code

BxC

Standard.

R10=0.1uH, 1R0=1.0uH, 100=10uH, 101=100uH, 102=1000uH.

K=±10%, L=±15%, M=±20%, N=±25%, Y=±30%

Marking: Black.1R0 and 1537(15 YY, 37 WW, follow production date).

L(mm)	G(mm)	H(mm)
12.5	5.4	3.5

Note: 1. The above PCB layout reference only.
2. Recommend solder paste thickness at 0.15mm and above.

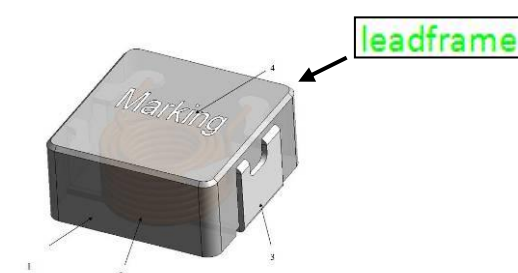
5. Specification

Part Number	Inductance L0 A(uH) ±20%	Heat Rating Current DC I rms.(A)		Saturation Current DC I sat. (A)		DCR (mΩ)Typ	DCR (mΩ)Max	Type
		Typ	Max	Typ	Max			
TMPA1004S-R15YN-D	0.15±30%	44.0	38.0	82.0	75.0	0.5	0.6	non-leadframe
TMPA1004S-R22MN-D	0.22	36.0	33.0	70.0	60.0	0.72	0.83	non-leadframe
TMPA1004S-R33MN-D	0.33	34.0	31.0	55.0	49.0	0.87	0.98	non-leadframe
TMPA1004S-R36MN-D	0.36	33.0	29.0	51.0	45.0	1.05	1.18	non-leadframe
TMPA1004S-R42MN-D	0.42	32.5	28.5	50.0	42.0	1.15	1.3	non-leadframe
TMPA1004S-R45MN-D	0.45	32.5	28.5	48.0	42.0	1.2	1.4	non-leadframe
TMPA1004S-R47MN-D	0.47	32.0	28.0	46.0	40.0	1.3	1.5	non-leadframe
TMPA1004S-R56MN-D	0.56	25.0	23.0	34.0	29.0	1.6	1.8	non-leadframe
TMPA1004S-R68MN-D	0.68	23.0	20.0	31.0	28.0	1.9	2.2	non-leadframe
TMPA1004S-R82MN-D	0.82	22.0	19.0	30.0	27.0	2.1	2.5	non-leadframe
TMPA1004S-R90MN-D	0.90	21.0	19.0	29.5	27.0	2.2	2.6	non-leadframe
TMPA1004S-1R0MN-D	1.00	20.0	18.0	29.0	26.0	2.9	3.25	non-leadframe
TMPA1004S-1R5MN-D	1.50	17.5	16.0	26.0	22.0	3.7	4.2	non-leadframe
TMPA1004S-1R8MN-D	1.80	16.5	15.0	23.0	20.5	5.1	5.7	leadframe
TMPA1004S-2R0MN-D	2.00	16.0	14.5	21.0	18.0	5.3	6.1	leadframe
TMPA1004S-2R2MN-D	2.20	15.0	13.0	20.0	16.0	5.8	6.7	leadframe
TMPA1004S-3R3MN-D	3.30	11.0	10.0	17.5	14.0	10.5	11.8	leadframe
TMPA1004S-4R7MN-D	4.70	8.8	8.0	15.2	13.0	15.8	19	leadframe
TMPA1004S-5R6MN-D	5.60	8.0	7.2	14.1	11.5	19	22.8	leadframe
TMPA1004S-6R8MN-D	6.80	7.8	6.8	12.2	11.0	22	24.5	leadframe
TMPA1004S-8R2MN-D	8.20	7.6	6.5	9.5	8.5	25	28	leadframe
TMPA1004S-100MN-D	10.0	7.5	6.1	8.6	7.5	27	30	leadframe
TMPA1004S-150MN-D	15.0	6.25	5.0	7.0	6.0	41	45	leadframe
TMPA1004S-220MN-D	22.0	5.0	4.1	6.2	5.5	58	66	leadframe
TMPA1004S-330MN-D	33.0	4.4	3.5	5.5	5.0	84	91	leadframe
TMPA1004S-470MN-D	47.0	3.5	3.0	4.0	3.7	125	143	leadframe
TMPA1004S-680MN-D	68.0	2.6	2.4	3.2	3.0	184	210	leadframe
TMPA1004S-820MN-D	82.0	2.3	2.1	3.0	2.8	240	270	leadframe
TMPA1004S-101MN-D	100	2.0	1.8	2.7	2.4	270	310	leadframe

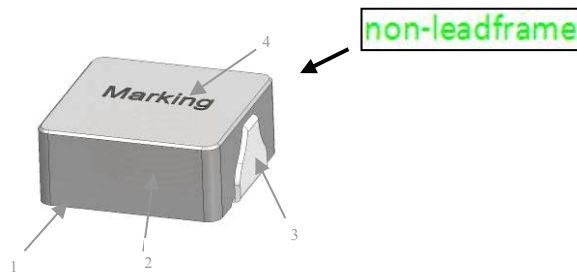
Note:

1. Test frequency : L_s : 100KHz /1.0V.
2. All test data referenced to 25°C ambient.
3. Testing Instrument(or equ) : L: HP4284A,CH11025,CH3302,CH1320,CH1320S LCR METER / Rdc:CH16502,Agilent33420A MICRO OHMMETER.
4. Heat Rated Current (I_{rms}) will cause the coil temperature rise approximately ΔT of 40°C
5. Saturation Current (I_{sat}) will cause L0 to drop approximately 30%.
6. The part temperature (ambient + temp rise) should not exceed 125°C under worst case operating conditions.Circuit design,component,PCB trace size and thickness,airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.
7. Special inquiries besides the above common used types can be met on your requirement.

6. Material List



NO	Items	Materials
1	Core	Alloy Powder .
2	Wire	Polyester Wire or equivalent.
3	Clip	100% Pb free solder(Ni+Sn---Plating)
4	Ink	Halogen-free ketone

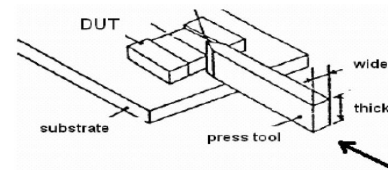


NO	Items	Materials
1	Core	Alloy Powder .
2	Wire	Polyester Wire or equivalent.
3	Solder	100% Pb free solder
4	Ink	Halogen-free ketone

7. Reliability and Test Condition

Item	Performance	Test Condition
Operating temperature	-40~+125℃ (Including self - temperature rise)	
Storage temperature	1. -10~+40℃,50~60%RH (Product without taping) 2. -40~+125℃ (on board)	
Electrical Performance Test		
Inductance	Refer to standard electrical characteristics list.	HP4284A,CH11025,CH3302,CH1320,CH1320S LCR Meter.
DCR		CH16502,Agilent33420A Micro-Ohm Meter.
Saturation Current (Isat)	Approximately ΔL 30%.	Saturation DC Current (Isat) will cause L0 to drop ΔL (%)
Heat Rated Current (Irms)	Approximately ΔT 40℃	Heat Rated Current (Irms) will cause the coil temperature rise ΔT (℃) without core loss. 1.Applied the allowed DC current 2.Temperature measured by digital surface thermometer
Reliability Test		
Life Test	Appearance : No damage. Inductance : within $\pm 10\%$ of initial value Q : Shall not exceed the specification value. RDC : within $\pm 15\%$ of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Temperature : 125 ± 2 ℃ (Inductor) Applied current : rated current Duration : 1000 ± 12 hrs Measured at room temperature after placing for 24 ± 2 hrs
Load Humidity		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Humidity : 85 $\pm 2\%$ R.H, Temperature : 85℃ ± 2 ℃ Duration : 1000hrs Min. with 100% rated current Measured at room temperature after placing for 24 ± 2 hrs
Moisture Resistance		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) 1. Baked at 50℃ for 25hrs, measured at room temperature after placing for 4 hrs. 2. Raise temperature to 65 ± 2 ℃ 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25℃ in 2.5hrs. 3. Raise temperature to 65 ± 2 ℃ 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25℃ in 2.5hrs,keep at 25℃ for 2 hrs then keep at -10℃ for 3 hrs 4. Keep at 25℃ 80-100%RH for 15min and vibrate at the frequency of 10 to 55 Hz to 10 Hz, measure at room temperature after placing for 1~2 hrs.
Thermal shock		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Condition for 1 cycle Step1 : -40 ± 2 ℃ 30 ± 5 min Step2 : 25 ± 2 ℃ ≤ 0.5 min Step3 : 125 ± 2 ℃ 30 ± 5 min Number of cycles : 500 Measured at room temperature after placing for 24 ± 2 hrs
Vibration		Oscillation Frequency: 10~2K~10Hz for 20 minutes Equipment : Vibration checker Total Amplitude:1.52mm $\pm 10\%$ Testing Time : 12 hours(20 minutes, 12 cycles each of 3 orientations)

TAIPAQ

Item	Performance	Test Condition															
Shock	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	<table><tr><th>Type</th><th>Peak value (g's)</th><th>Normal duration (D) (ms)</th><th>Wave form</th><th>Velocity change (Vi)ft/sec</th></tr><tr><td>SMD</td><td>50</td><td>11</td><td>Half-sine</td><td>11.3</td></tr><tr><td>Lead</td><td>50</td><td>11</td><td>Half-sine</td><td>11.3</td></tr></table>	Type	Peak value (g's)	Normal duration (D) (ms)	Wave form	Velocity change (Vi)ft/sec	SMD	50	11	Half-sine	11.3	Lead	50	11	Half-sine	11.3
Type	Peak value (g's)	Normal duration (D) (ms)	Wave form	Velocity change (Vi)ft/sec													
SMD	50	11	Half-sine	11.3													
Lead	50	11	Half-sine	11.3													
Bending		Shall be mounted on a FR4 substrate of the following dimensions: >=0805:40x100x1.2mm <0805:40x100x0.8mm Bending depth: >=0805:1.2mm <0805:0.8mm duration of 10 sec.															
Solderability	More than 95% of the terminal electrode should be covered with solder ◦	Preheat: 150℃,60sec. ◦ Solder: Sn96.5% Ag3% Cu0.5% Temperature: 245±5℃ ◦ Flux for lead free: Rosin. 9.5% ◦ Dip time: 4±1sec ◦ Depth: completely cover the termination															
Resistance to Soldering Heat		Number of heat cycles: 1 <table><tr><th>Temperature (℃)</th><th>Time(s)</th><th>Temperature ramp/immersion and emersion rate</th></tr><tr><td>260 ±5(solder temp)</td><td>10 ±1</td><td>25mm/s ±6 mm/s</td></tr></table>	Temperature (℃)	Time(s)	Temperature ramp/immersion and emersion rate	260 ±5(solder temp)	10 ±1	25mm/s ±6 mm/s									
Temperature (℃)	Time(s)	Temperature ramp/immersion and emersion rate															
260 ±5(solder temp)	10 ±1	25mm/s ±6 mm/s															
Terminal Strength	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles With the component mounted on a PCB with the device to be tested, apply a force (>0805:1kg , <=0805:0.5kg)to the side of a device being tested. This force shall be applied for 60 +1 seconds. Also the force shall be applied gradually as not to apply a shock to the component being tested. 															

Note : When there are questions concerning measurement result : measurement shall be made after 48 ± 2 hours of recovery under the standard condition.

8. Soldering and Mounting

(1) Soldering

Mildly activated rosin fluxes are preferred. The minimum amount of solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. TAI-TECH terminations are suitable for re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

(2) Solder re-flow:

Recommended temperature profiles for re-flow soldering in Figure 1.

(3) Soldering Iron:

Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

- Preheat circuit and products to 150°C
- Never contact the ceramic with the iron tip
- Use a 20 watt soldering iron with tip diameter of 1.0mm
- 355°C tip temperature (max)
- 1.0mm tip diameter (max)
- Limit soldering time to 4~5sec.

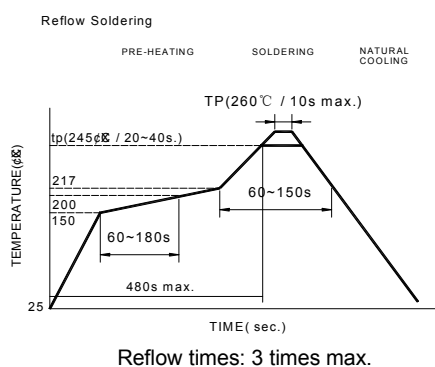


Fig.1

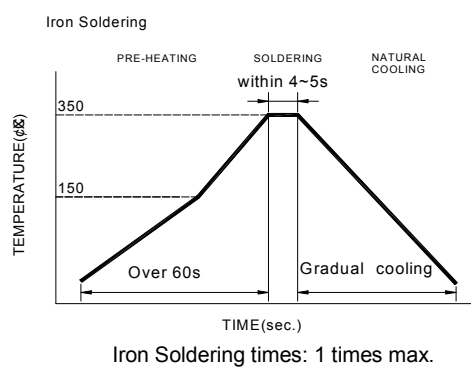


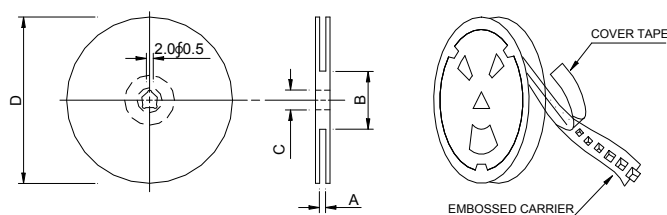
Fig.2

9. Friendly reminder

- (1) When there are questions concerning measurement result : measurement shall be made after 48 ± 2 hours of recovery under the standard condition
- (2) This power choke coil itself does not have any protective function in abnormal condition such as overload, short-circuit and open-circuit conditions, etc. Therefore, it shall be confirmed as the end product that there is no risk of smoking, fire, dielectric withstand voltage, insulation resistance, etc. in abnormal conditions to provide protective devices and/or protection circuit in the end product.
- (3) When this power choke coil was used in a similar or new product to the original one, sometimes it might not be able to satisfy the specifications due to different condition of use.
- (4) Dielectric withstanding test with higher voltage than specific value will damage insulating material and shorten its life.
- (5) This power choke coil must not be used in wet condition by water, coffee or any liquid because insulation strength becomes very low in this condition.
- (6) Please consult our company to confirm the reliability of the process required to wash or use or exposure to a chemical solvent used in this product.

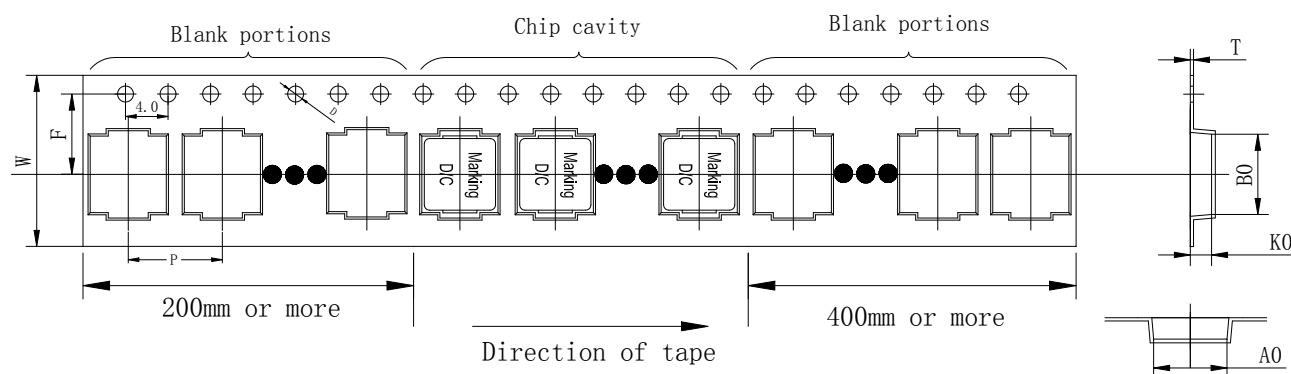
10. Packaging Information

(1) Reel Dimension



Type	A(mm)	B(mm)	C(mm)	D(mm)
13"x24mm	24.4±2/-0	100±2	13±0.5/-0.2	330

(2) Tape Dimension

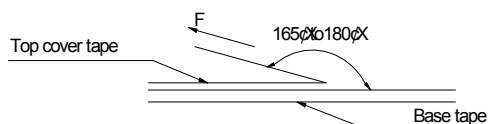


Series	Size	Bo(mm)	Ao(mm)	Ko(mm)	P(mm)	W(mm)	F(mm)	t(mm)	D(mm)
TMPA	1004	11.6±0.1	10.4±0.1	4.5±0.1	16.0±0.1	24±0.3	11.5±0.1	0.35±0.05	1.5±0.1

(3) Packaging Quantity

TMPA	1004
Chip / Reel	500
Inner box	1000
Carton	4000

(4) Tearing Off Force



The force for tearing off cover tape is 10 to 130 grams in the arrow direction under the following conditions(referenced ANSI/EIA-481-C-2003 of 4.11 standard).

Room Temp. (°C)	Room Humidity (%)	Room atm (hPa)	Tearing Speed mm/min
5~35	45~85	860~1060	300

Application Notice

• Storage Conditions

To maintain the solderability of terminal electrodes:

1. TAIPAQ products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
2. Temperature and humidity conditions: Less than 40°C and 60% RH.
3. Recommended products should be used within 12 months from the time of delivery.
4. The packaging material should be kept where no chlorine or sulfur exists in the air.

• Transportation

1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
2. The use of tweezers or vacuum pick up is strongly recommended for individual components.
3. Bulk handling should ensure that abrasion and mechanical shock are minimized.

11. Typical Performance Curves

